

P/N: TC40-11EWA

HIGH EFFICIENCY RED

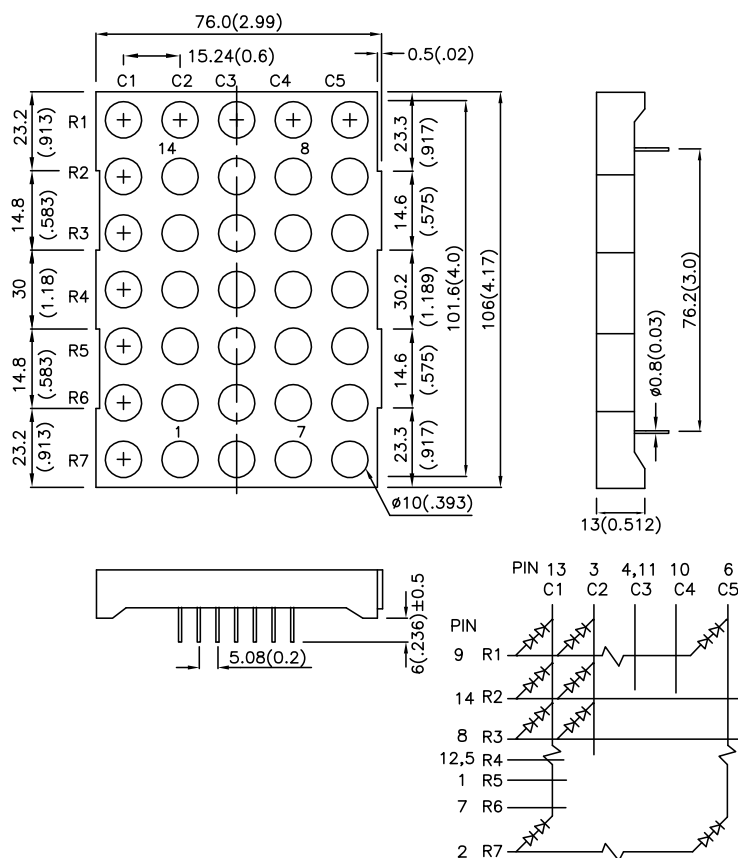
Features

- 4.0 INCH MATRIX HEIGHT.
- DOT SIZE 10mm.
- LOW CURRENT OPERATION.
- HIGH CONTRAST AND LIGHT OUTPUT.
- COMPATIBLE WITH ASCII AND EBCDIC CODES.
- STACKABLE HORIZONTALLY.
- COLUMN CATHODE AVAILABLE.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- MULTICOLOR AVAILABLE.
- MECHANICALLY RUGGED.
- STANDARD : GRAY FACE, WHITE DOT.
- RoHS COMPLIANT.

Description

The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
2. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) @ 10mA		Description
			Min.	Typ.	
TC40-11EWA	HIGH EFFICIENCY RED (GaAsP/GaP)	WHITE DIFFUSED	3000	16000	Column Cathode

Electrical / Optical Characteristics at TA=25°C

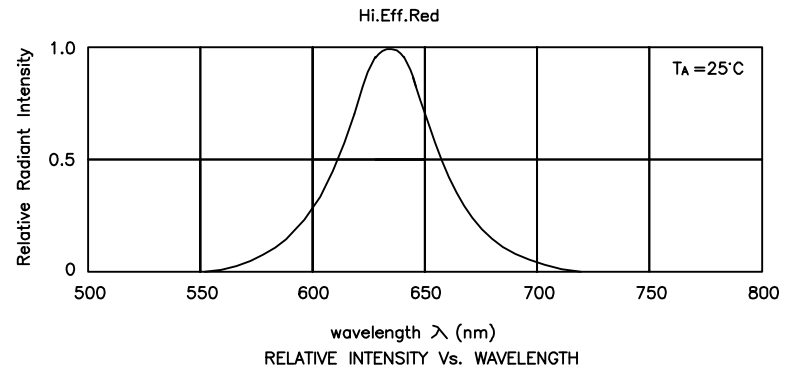
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	High Efficiency Red	627		nm	IF=20mA
λ_D	Dominant Wavelength	High Efficiency Red	625		nm	IF=20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	High Efficiency Red	45		nm	IF=20mA
C	Capacitance (Per Chip)	High Efficiency Red	15		pF	VF=0V;f=1MHz
VF	Forward Voltage (Per Dot)	High Efficiency Red	4.0	5.0	V	IF=20mA
IR	Reverse Current (Per Dot)	High Efficiency Red		10	uA	VR = 10V

Absolute Maximum Ratings at TA=25°C

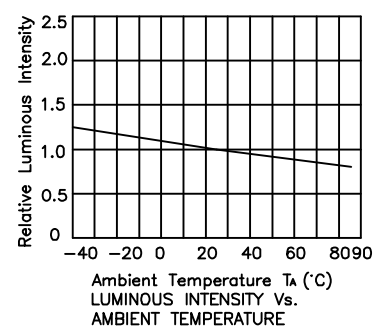
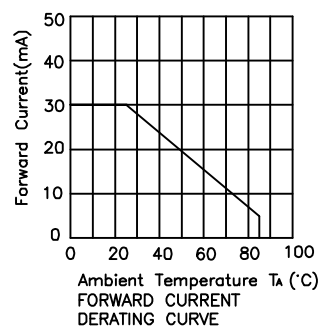
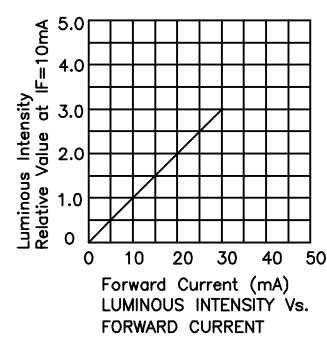
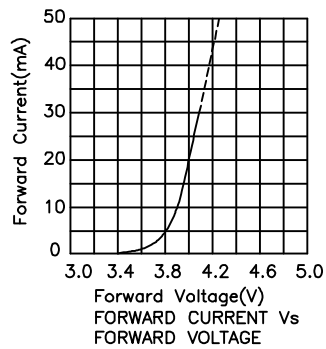
Parameter	High Efficiency Red	Units
Power dissipation (Per Dot)	150	mW
DC Forward Current (Per Dot)	30	mA
Peak Forward Current [1] (Per Dot)	160	mA
Reverse Voltage (Per Dot)	10	V
Operating/Storage Temperature	-40°C To +85°C	
Lead Solder Temperature[2]	260°C For 5 Seconds	

Notes:

- 1/10 Duty Cycle, 0.1ms Pulse Width.
- 2mm below package base.

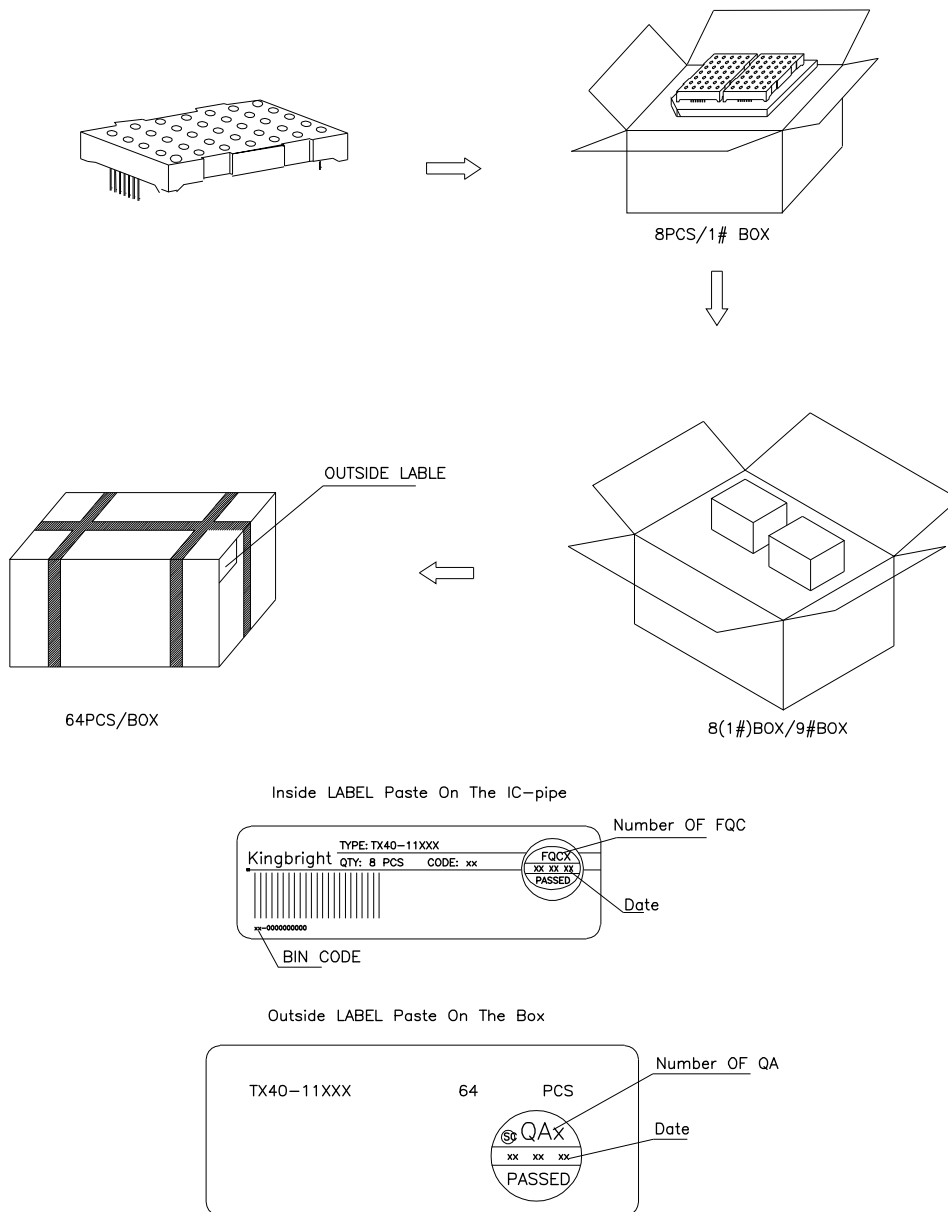


High Efficiency Red TC40-11EWA



PACKING & LABEL SPECIFICATIONS

TC40-11EWA



Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity/ luminous flux, or wavelength), the typical accuracy of the sorting process is as follows:

1. Wavelength: +/-1nm
2. Luminous Intensity/ luminous flux: +/-15%
3. Forward Voltage: +/-0.1V

Note: Accuracy may depend on the sorting parameters.